

Vishay Semiconductors

Dual 1 Form A Solid State Relay

Features

- Dual Channel (LH1550)
- Current Limit Protection
- Isolation Test Voltage 5300 V_{RMS}
- Typical R_{ON} 28 Ω
- Load Voltage 350 V
- Load Current 90 mA
- High Surge Capability
- Linear, AC/DC Operation
- Clean Bounce Free Switching
- Low Power Consumption
- SMD Lead Available on Tape and Reel

Agency Approvals

- UL File No. E52744 System Code H or J
- CSA Certification 093751
- BSI/BABT Cert. No. 7980
- DIN EN 60747-5-5 (VDE 0884):2003-01 Available with Option 1
- FIMKO Approval

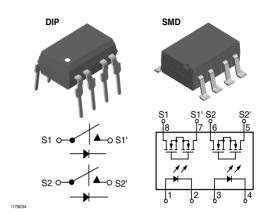
Applications

General Telecom Switching

- On/off Hook Control
- Ring Delay
- Dial Pulse
- Ground Start
- Ground Fault Protection

Instrumentation

Industrial Controls



Description

The LH1533 (Dual 1 Form A) relays are SPST normally open switches that can replace electromechanical relays in many applications. They are constructed using a GaAIAs LED for actuation control and an integrated monolithic die for the switch output. The die, fabricated in a high-voltage dielectrically isolated technology is comprised of a photodiode array, switch control circuitry, and MOSFET switches. In addition, the relays employ current-limiting circuitry, enabling them to pass FCC 68.302 and other regulatory surge requirements when overvoltage protection is provided.

Order Information

Part	Remarks		
LH1533AAC	SMD-8, Tubes		
LH1533AACTR	SMD-8, Tape and Reel		
LH1533AB	DIP-8, Tubes		

Absolute Maximum Ratings, T_{amb} = 25 °C

Stresses in excess of the absolute Maximum Ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute Maximum Ratings for extended periods of time can adversely affect reliability.

SSR

Parameter	Test condition	Symbol	Value	Unit
LED continuous forward current		١ _F	50	mA
LED reverse voltage	$I_R \le 10 \ \mu A$	V _R	5.0	V
Output operation: dc or peak ac load voltage	$I_L \le 50 \ \mu A$	VL	350	V





Parameter	Test condition	Symbol	Value	Unit
Continuous dc load current: one pole operating		ΙL	90	mA
Continuous dc load current: two pole operating		١ _L	70	mA
Ambient operating temperature range		T _{amb}	- 40 to + 85	°C
Storage temperature range		T _{stg}	- 55 to + 150	°C
Pin soldering temperature	t = 10.0 s max	T _{sld}	260	°C
Input/output isolation voltage		V _{ISO}	5300	V _{RMS}
Power dissipation (continuous)		P _{diss}	600	mW

Electrical Characteristics, T_{amb} = 25 °C Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluations. Typical values are for information only and are not part of the testing requirements.

Input

Parameter	Test condition	Symbol	Min	Тур.	Max	Unit
LED forward current, switch turn-on	I _L = 100 mA, t = 10 ms	I _{Fon}			2.5	mA
LED forward current, switch turn-off	V _L = ± 300 V	I _{Foff}	0.01	1.1		mA
LED forward voltage	I _F = 5.0 mA	V _F	0.9	1.2	1.4	V

Output

Parameter	Test condition	Symbol	Min	Тур.	Max	Unit
ON-resistance	$I_{F} = 5.0 \text{ mA}, I_{L} = \pm 90 \text{ mA}$	R _{ON}	25	28	50	Ω
Current limit	$I_F = 5.0 \text{ mA}, t = 5.0 \text{ ms}, V_L = 13 \text{ V}$	I _{LMT}	150	200	270	mA
Off-state leakage current	$I_{F} = 0 \text{ mA}, V_{L} = \pm 350 \text{ V}$				1.0	nA

Transfer

Parameter	Test condition	Symbol	Min	Тур.	Max	Unit
Turn-on time	$I_{F} = 5.0 \text{ mA}, I_{L} = 50 \text{ mA}$	t _{on}			3.0	ms
Turn-off time	$I_{F} = 5.0 \text{ mA}, I_{L} = 50 \text{ mA}$	t _{off}			3.0	ms



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Typical Characteristics (T_{amb} = 25 °C unless otherwise specified)

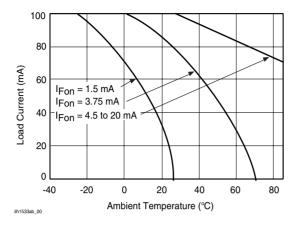


Figure 1. Recommended Operating Conditions

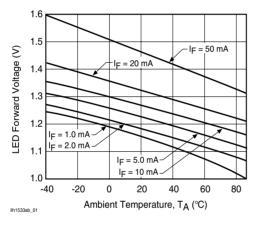


Figure 2. LED Voltage vs. Temperature

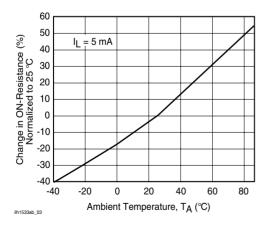


Figure 3. ON-Resistance vs. Temperature

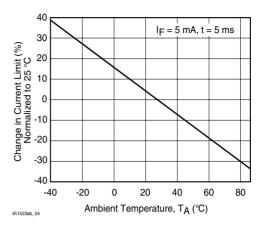


Figure 4. Current Limit vs. Temperature

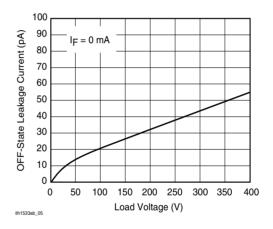
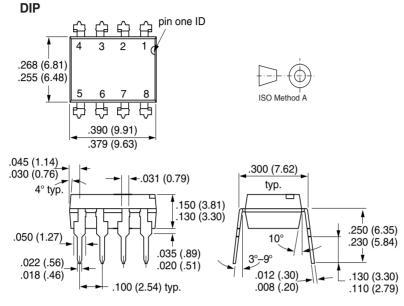


Figure 5. Leakage Current vs. Applied Voltage

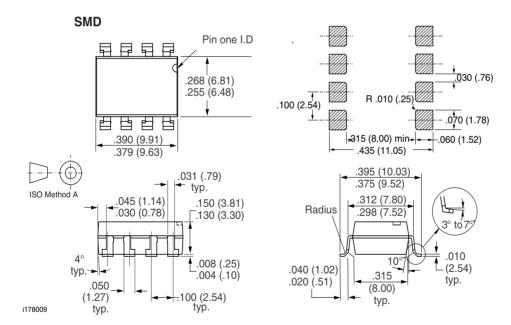
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Package Dimensions in Inches (mm)



i178008





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Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operatingsystems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

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Datasheets for electronics components.